

این دیتاشیت توسط توکل الکترونیک تهیه و ارائه شده است.
جهت مشاهده قیمت، موجودی و ثبت سفارش این قطعه به وبسایت توکل الکترونیک مراجعه فرمایید.



مشاهده قیمت و خرید

برای خرید و مشاهده سایر محصولات کلیک کنید



DISCRETE SEMICONDUCTORS

DATA SHEET

BSS92

P-channel enhancement mode
vertical D-MOS transistor

Product specification
Supersedes data of April 1995
File under Discrete Semiconductors, SC13b

1997 Jun 19

P-channel enhancement mode
vertical D-MOS transistor

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FEATURES

- Direct interface to C-MOS, TTL, etc.
- High-speed switching
- No secondary breakdown.

APPLICATIONS

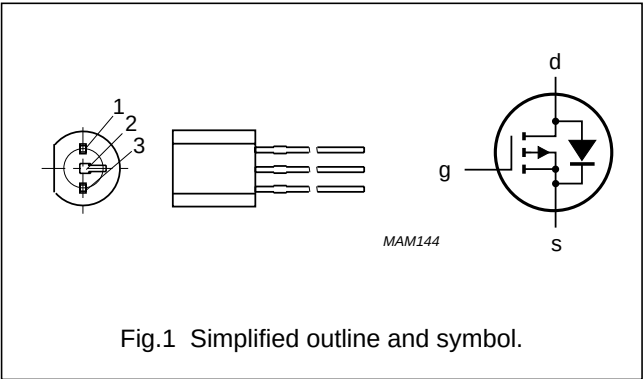
- Line current interrupter in telephony applications
- Relay, high speed and line transformer drivers.

DESCRIPTION

P-channel enhancement mode vertical D-MOS transistor in a TO-92 (SOT54) variant package.

PINNING - TO-92 (SOT54) variant

PIN	SYMBOL	DESCRIPTION
1	g	gate
2	d	drain
3	s	source



QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{DS}	drain-source voltage (DC)		–	–	–240	V
V_{GSO}	gate-source voltage (DC)	open drain	–	–	±20	V
I_D	drain current (DC)		–	–	–150	mA
R_{DSon}	drain-source on-state resistance	$I_D = -100\text{ mA}; V_{GS} = -10\text{ V}$	–	10	20	Ω
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ }^\circ\text{C}$	–	–	1	W
$ y_{fs} $	forward transfer admittance	$V_{DS} = -25\text{ V}; I_D = -100\text{ mA}$	60	200	–	mS

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{DS}	drain-source voltage (DC)		–	–240	V
V_{GSO}	gate-source voltage (DC)	open drain	–	± 20	V
I_D	drain current (DC)		–	–150	mA
I_{DM}	peak drain current		–	–600	mA
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$; note 1	–	1	W
T_{stg}	storage temperature		–55	+150	°C
T_j	operating junction temperature		–	150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	125	K/W

Note to the Limiting values and Thermal characteristics

- Device mounted on a printed-circuit board, maximum lead length 4 mm; mounting pad for drain lead minimum 10 mm × 10 mm.

CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0$; $I_D = -250\text{ }\mu\text{A}$	–240	–	–	V
V_{GSth}	gate-source threshold voltage	$V_{DS} = V_{GS}$; $I_D = -1\text{ mA}$	–0.8	–	–2.8	V
I_{DSS}	drain-source leakage current	$V_{GS} = 0$; $V_{DS} = -60\text{ V}$	–	–	–200	nA
		$V_{GS} = 0$; $V_{DS} = -200\text{ V}$	–	–	–60	μA
I_{GSS}	gate leakage current	$V_{DS} = 0$; $V_{GS} = \pm 20\text{ V}$	–	–	± 100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = -10\text{ V}$; $I_D = -100\text{ mA}$	–	10	20	Ω
$ y_{fs} $	forward transfer admittance	$V_{DS} = -25\text{ V}$; $I_D = -100\text{ mA}$	60	200	–	mS
C_{iss}	input capacitance	$V_{GS} = 0$; $V_{DS} = -25\text{ V}$; $f = 1\text{ MHz}$	–	65	–	pF
C_{oss}	output capacitance	$V_{GS} = 0$; $V_{DS} = -25\text{ V}$; $f = 1\text{ MHz}$	–	20	–	pF
C_{rss}	reverse transfer capacitance	$V_{GS} = 0$; $V_{DS} = -25\text{ V}$; $f = 1\text{ MHz}$	–	6	–	pF

Switching times (see Figs 2 and 3)

t_{on}	turn-on time	$V_{GS} = 0\text{ to }-10\text{ V}$; $V_{DD} = -50\text{ V}$; $I_D = -250\text{ mA}$	–	5	–	ns
t_{off}	turn-off time	$V_{GS} = -10\text{ to }0\text{ V}$; $V_{DD} = -50\text{ V}$; $I_D = -250\text{ mA}$	–	20	–	ns

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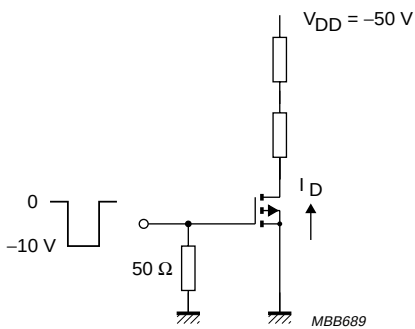


Fig.2 Switching times test circuit.

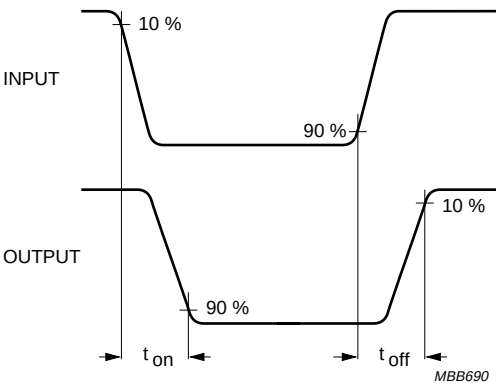


Fig.3 Input and output waveforms.

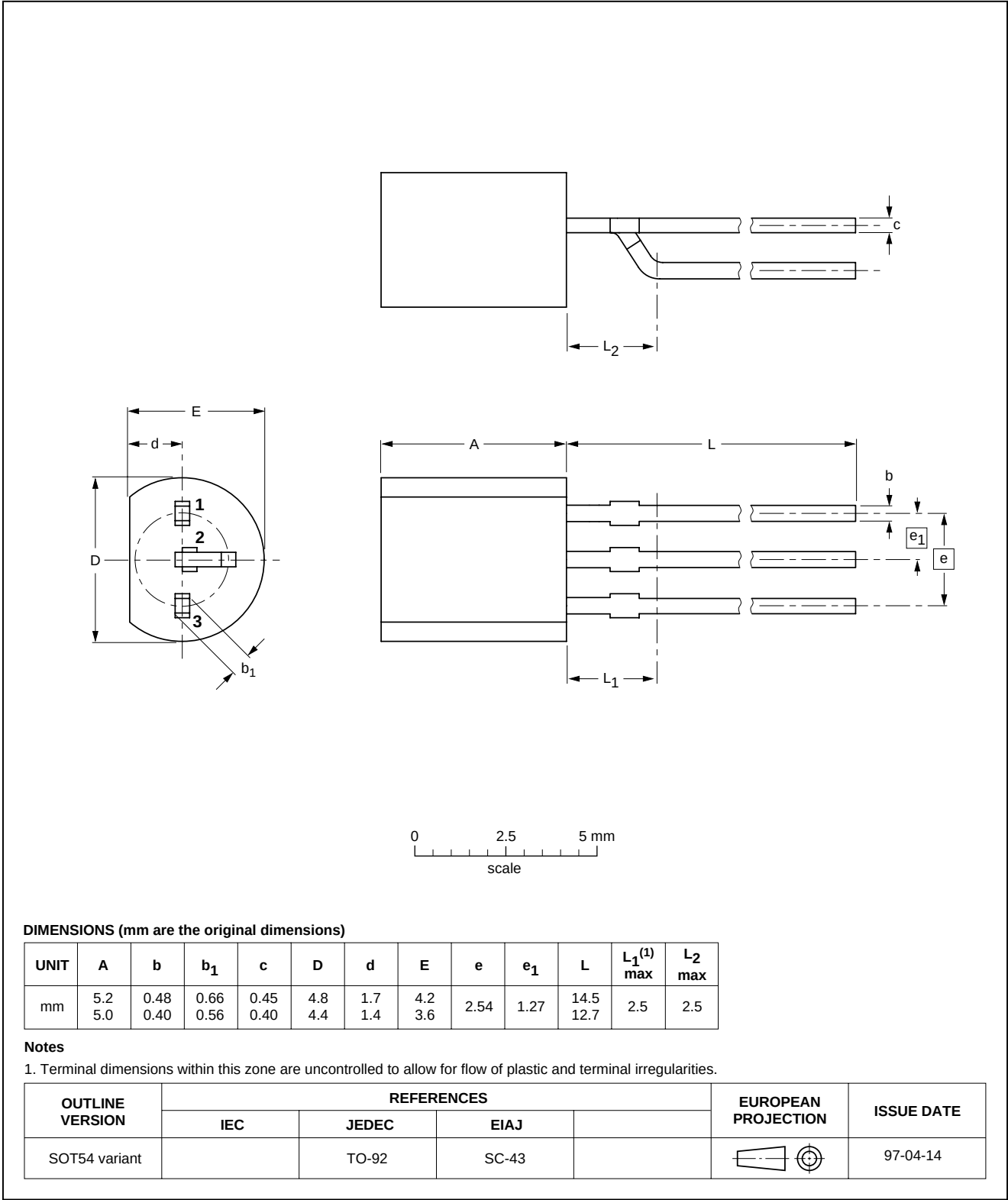
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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads (on-circle)

SOT54 variant



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BSS92**DEFINITIONS**

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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